



Original Article

## Aniline adsorption on the surface of a BN nanotube: Computational study

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### Abstract:

Electrical sensitivity of a boron nitride nanotube (BNNT) was examined toward aniline ( $C_6H_5NH_2$ ) molecule by using density functional theory (DFT) calculations at the B3LYP/6-31G (d) level, and it was found that the adsorption energy ( $E_{ad}$ ) of aniline on the pristine nanotubes is about  $-19.03\text{kcal/mol}$ . But when nanotube has been doped with Si and Al atoms, the adsorption energy of aniline molecule was increased. Calculation showed that when the nanotube is doped by Al, the adsorption energy is about  $-27.73\text{kcal/mol}$  and also the amount of HOMO/LUMO energy gap ( $E_g$ ) will reduce significantly. Boron nitride nanotube is a suitable adsorbent for aniline and can be used in separation processes of aniline. It is seen that nanotube (BNNT) is a suitable semiconductor after doping, and the doped BNNT in the presence of aniline an electrical signal is generated directly and therefore can potentially be used for aniline sensors.

**Keywords:** Sensor, Nanotube, DFT, Aniline

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## Introduction:

Aniline comes to light as a toxic compound for human [1,2]. It was reported that the amount of aniline that went into the environment has been estimated at 30000 tons annually [3], thus aniline detection and separation is very important. Since the discovery of carbon nanotube (CNT) by Iijima [4] the properties and applications of this novel material have been investigated extensively [5-7]. CNTs have recently emerged as a promising substitute for materials of different properties and various applications in hydrogen storage, gas sensors, textiles and many more[8,9]. Boron nitride nanotube (BNNT) has unique properties of a semiconductor behavior. The reason for such behavior is the total atomic number of B and N [10-12]. An interesting case for studying about these BNNTs is investigating their composite type [13]. BNNTs unique properties including tensile strength, stiffness and deformation are the features of this nanotube [14-16]. Previously adsorption of different molecules toward nanostructures has been studied [17-20]. In this study, the adsorption of aniline on the pristine case BNNT while Si and Al atoms are in its structure has been investigated.

## Computational methods:

Computation procedures are include the following:

We have optimized the aniline molecule and BNNT at the B3LYP/6-31G (d) level of theory. BNNT is made up of 30N, 30B atoms were saturated by 10 hydrogen atoms which are in initial and end part of nanotube. The reason for this act had been done to decrease the boundary effects and totally nanotube is involving 70 (Fig.1).

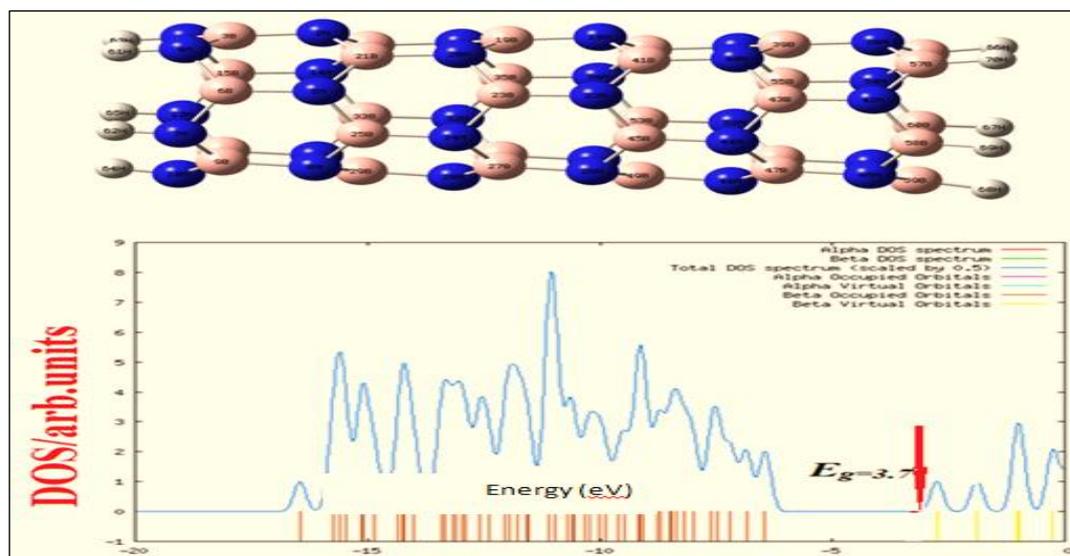
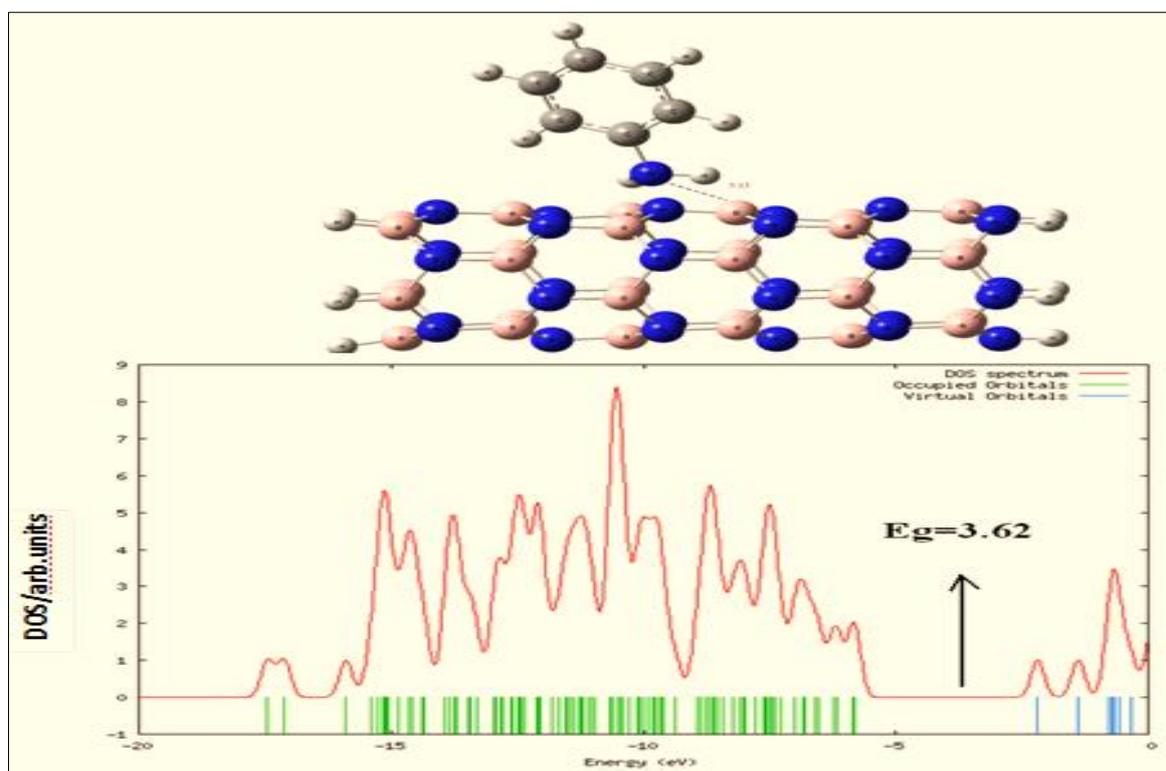


Figure1: BNNT and DOS diagram for  $E_g$  nanotube .

The BNNT that has been selected is zigzag (5,0) type and GAMESS software [21] is used to perform these calculations. The B3LYP is demonstrated to be a reliable and commonly used functional in the study of different nanostructures [22-24]. We made aniline molecule from different positions of the site to be close to the nanotube (Fig.2) and its adsorption has been calculated by using the Eq.(1).

$$E_{ad} = E_{\text{Nanotube} + \text{Aniline}} - [E_{\text{Aniline}} + E_{\text{Nanotube}}] + \delta_{\text{BSSE}} \quad (1)$$

According to the mentioned equation  $E_{\text{Aniline}}$  is aniline molecule's energy,  $E_{\text{Nanotube}}$  is the nanotube energy and  $E_{\text{Nanotube} + \text{Aniline}}$  is the nanotube's energy with aniline. In addition,  $\delta_{\text{BSSE}}$  is representing the basis set super position error. In the following steps Si and Al atoms in the nanotube structure have been doped to examine the aniline adsorption on the nanotube and conductivity that which is doping with Si and Al atoms.



**Figure 2:** Aniline adsorption on the BNNT and DOS diagram for observing  $E_g$  of nanotube. Distance is in Å

## Results and discussion:

Fig.1, shows the structure of boron nitride nanotube (BNNT), in order to obtain the most stable adsorption mode of aniline molecule on different positions of BNNT, the most stable configuration is shown in Fig.2, that nitrogen atom of aniline is 3.13 Å far from boron atom of the nanotube. Detailed information of the structure and electronic properties of the BNNT including the HOMO/LUMO energy gap ( $E_g$ ) are shown in Table1 in which adsorption energy ( $E_{ad}$ ) for mentioned configuration of aniline and nanotube is about –

19.03kcal/mol and then we calculated the HOMO/LUMO energy gap ( $E_g$ ) for pristine nanotube since the aniline molecule is adsorbed on the nanotubes (Table1). Diagram which shows HOMO/LUMO energy gap ( $E_g$ ) has been calculated, and the diagram which shows  $E_g$  has been obtained by using density of state (DOS) software.

**Table1.  $E_{ad}$ (kcal/mol), eV for the others**

System	$E_{ad}$	$E_{HOMO}$	$E_{LUMO}$	$E_g$
BNNT	-	-6.45	-2.76	<b>3.69</b>
Ani/BNNT	-19.03	-5.81	-2.19	<b>3.62</b>
Si <sub>N</sub> -Ani	-24.91	-5.19	-2.36	<b>2.89</b>
Si <sub>B</sub>	-	-5.75	-2.68	<b>3.07</b>
Si <sub>B</sub> -Ani	-10.85	-5.06	-2.55	<b>2.51</b>
Al <sub>N</sub>	-	-5.54	-3.00	<b>2.54</b>
Al <sub>N</sub> -Ani	-27.73	-4.94	-2.27	<b>2.67</b>
Al <sub>B</sub>	-	-6.42	-2.67	<b>3.75</b>
Al <sub>B</sub> -Ani	-47.75	-6.12	-2.28	<b>3.84</b>

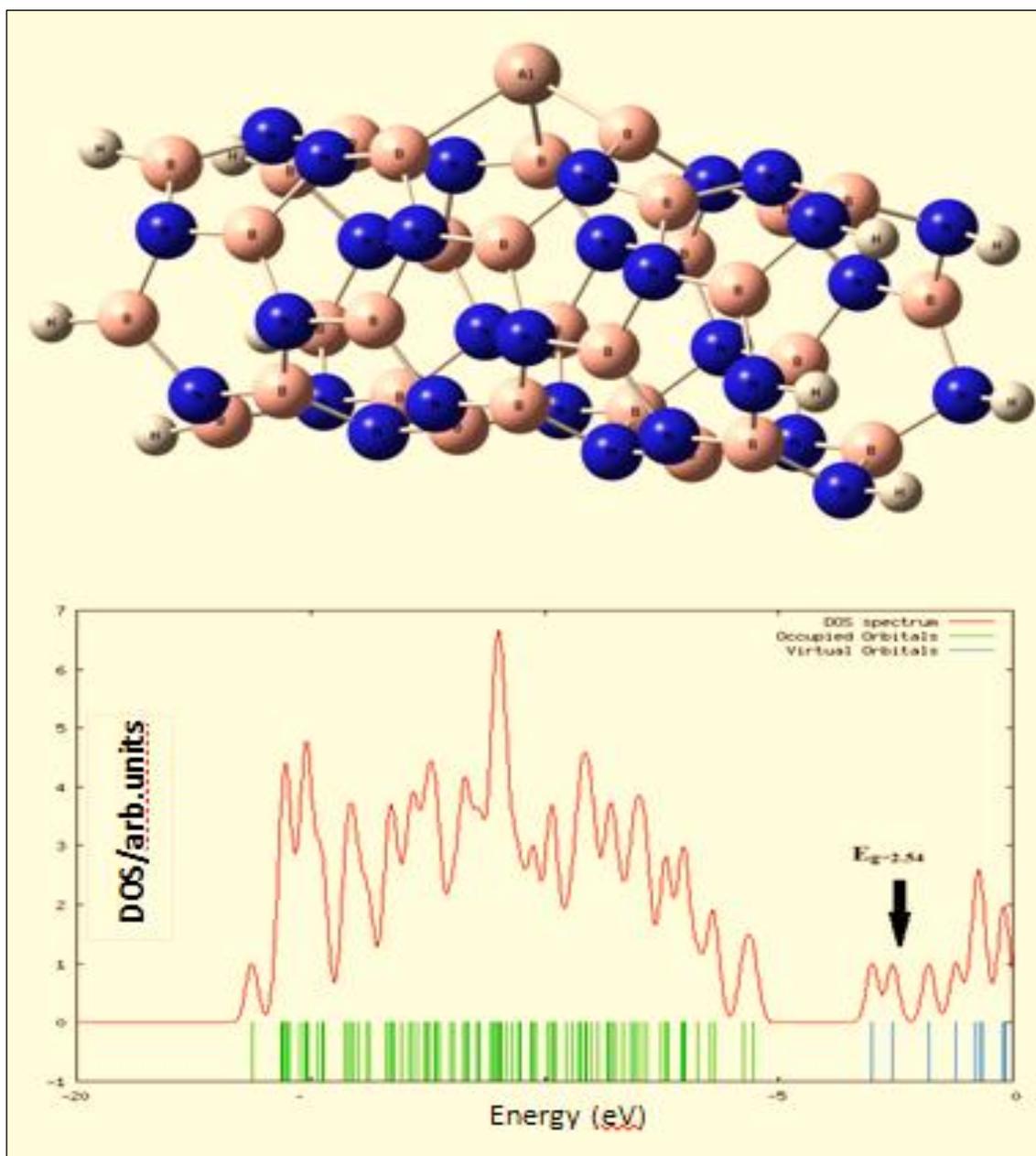
### Adsorption of C<sub>6</sub>H<sub>5</sub>NH<sub>2</sub> on Al doped BNNT:

To examine the sensitivity of the adsorption of BNNT of C<sub>6</sub>H<sub>5</sub>(NH)<sub>2</sub> as an adsorbent for C<sub>6</sub>H<sub>5</sub>(NH)<sub>2</sub> its examining has been done two times, once B atom doped by Al atom and other time N atom by Al atom has been doped. Doped calculation of Al on BNNT shows that the value of HOMO/LUMO energy gap ( $E_g=2.54$ eV) is less than the pristine nanotube with  $E_g=3.69$ eV (Fig.2) and the best adsorption energy ( $E_{ad}=-47.75$ kcal/mol) is obtained when Al sitting instead of N and aniline has been adsorbed. When Al is doped on BNNT in the presence of aniline electrical signal is generation directly and therefore can potentially be used for aniline sensors. DOS diagram clearly shows that when Al is doped on the BNNT (Fig.3), it will become a semiconductor  $E_g=2.67$ eV. Optimization of these types of interactions is desirable for gas detection because such strong interaction means that the BNNT is a suitable absorbent for aniline molecule (Fig.4). If  $E_{ad}$  is significantly increased then it expect that recovery will be so long, meanwhile according to transition state theory and recovery time can be explain as Eq.(2)

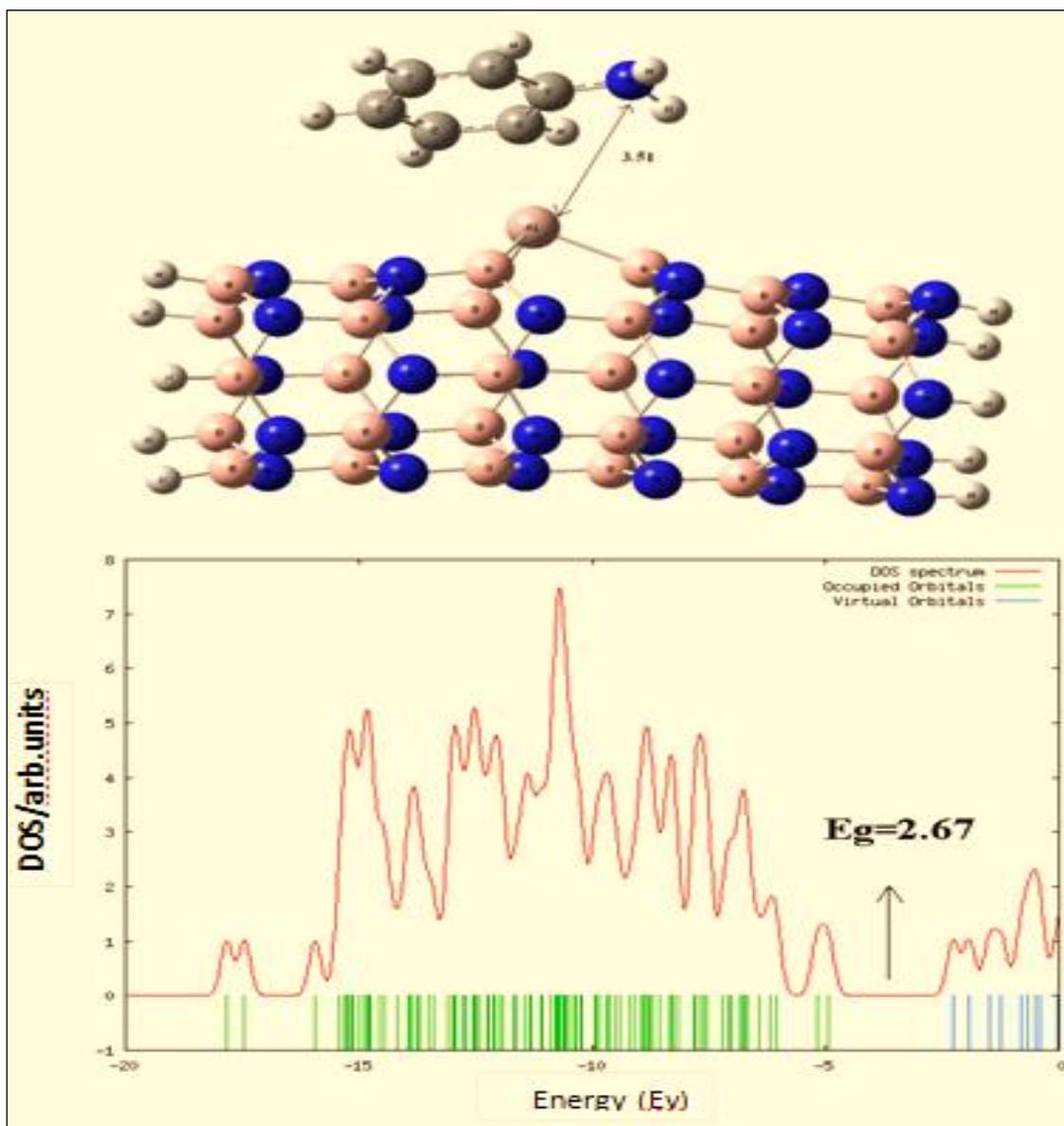
$$\tau = \nu_0^{-1} \exp(-E_{ad}/kT) \quad (2)$$

where T is the temperature, k is the Boltzmann's constant, and  $\nu_0$  is the attempt frequency.

According to this equation as often as adsorption energy ( $E_{ad}$ ) is increasing the recovery time becomes longer and calculation in Table1.



**Figure3:** Doped nanotube by  $Al_N$  and DOS diagram for  $E_g$ . Distance is in Å.



**Figure 4:** Aniline adsorption on doped nanotube by  $Al_N$  and DOS diagram for observing  $E_g$  of nanotube. Distance is in  $\text{\AA}$ .

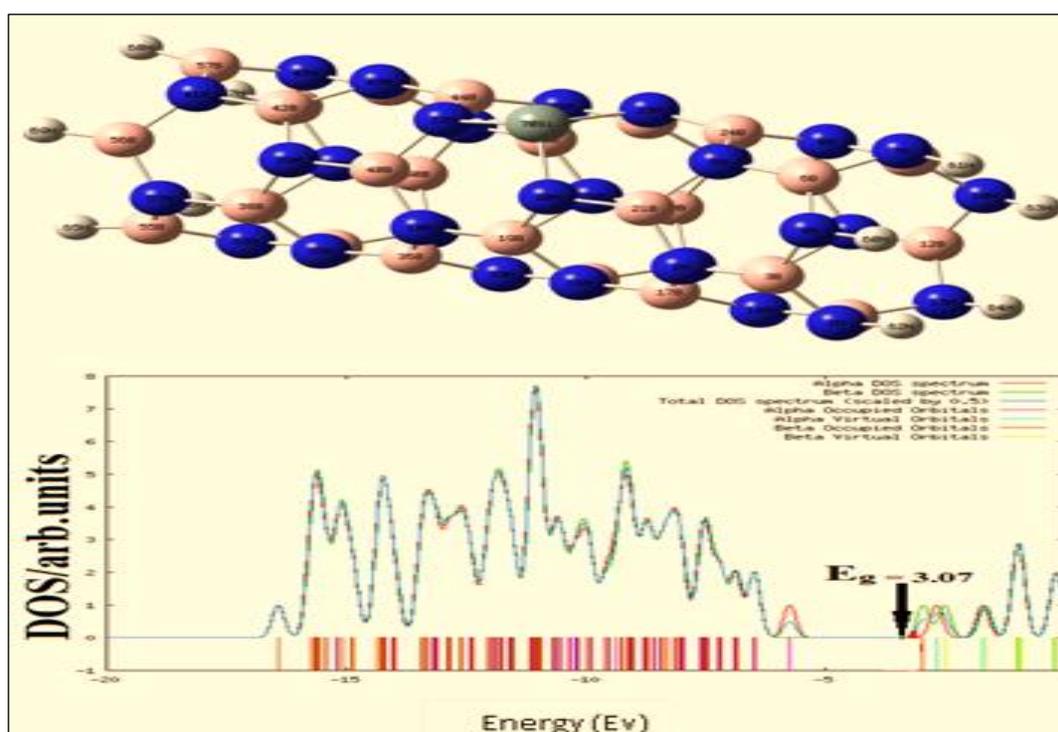
### Adsorption of $C_6H_5NH_2$ on Si doped BNNT:

At this stage doping has been studied with another element. First, instead of B atom in the boron nitride nanotube a Si atom and then instead of N atom a Si atom replaced in a nanotube (Fig.5), and then

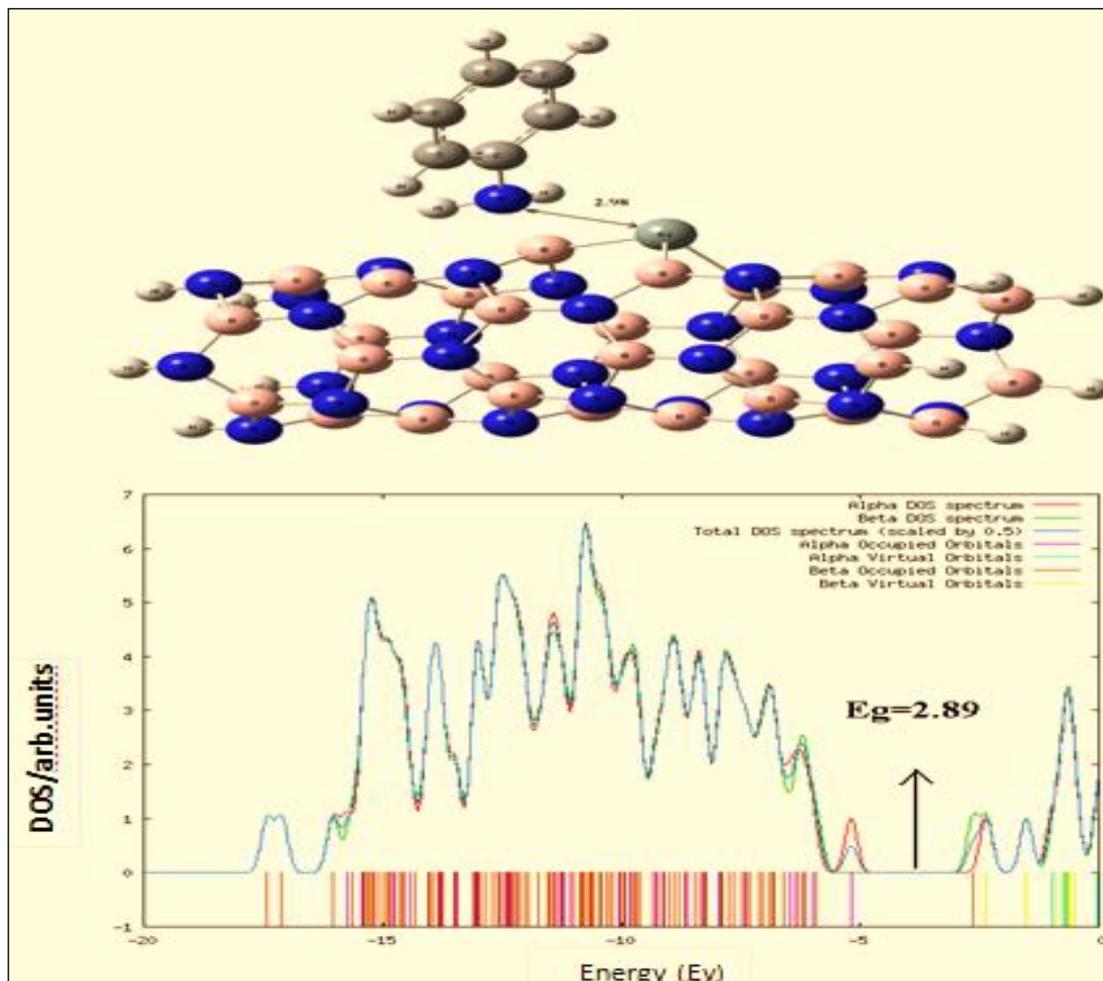
geometrical structures and electronic properties of BNNT are doped and their adsorption behavior are studied (Fig.5). Computations showed that when N is replaced by Si in BNNT the HOMO/LUMO energy gap will become less of  $E_g=2.54\text{eV}$ . When Si is sitting of N, and the adsorption energy of aniline on nanotube is more ( $E_{ad}=-24.91\text{kcal/mol}$ ) than when we just use the pristine nanotube ( $E_{ad}=-19.03\text{kcal/mol}$ ). After adsorption of  $\text{C}_6\text{H}_5(\text{NH})_2$  on the mentioned nanotube that has been doped by Si the HOMO/LUMO energy gap ( $E_g=2.89\text{eV}$ ) will be decrease the pristine of nanotube and therefore a substantial increase will occur in conductivity and this phenomenon can be explain as Eq.(3), [22]

$$\sigma \propto \exp(-E_g / 2kT) \quad (3)$$

where  $\sigma$  is conductance,  $T$  is temperature,  $k$  is Boltzmann constant. According to this equation as often as  $E_g$  is smaller it leads the conductivity to be more it can be concluded that therefore Si is a not suitable for doping in BNNT.



**Figure 5:** Doped nanotube by  $\text{Si}_B$  and DOS diagram for  $E_g$  of nanotube.



**Figure 6.** Aniline adsorption on doped nanotube by  $\text{Si}_N$  and DOS diagram for observing of  $E_g$  nanotube. Distance is in  $\text{\AA}$ .

## Conclusion:

The adsorption of an aniline ( $\text{C}_6\text{H}_5\text{NH}_2$ ) molecules on the surface of BNNT (boron nitride nanotube) has been studied by using density functional theory (DFT) and then we doped the Al atom in the structure of the nanotube, the results show it is clearly possible to modify the nanotube as an effective adsorbent of aniline molecule in gas sensors which are sensitive about aniline. These results may be open a new gate to chemically modify the nanotubes in a way to expand the fields of their applications in industry and technology.

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